

## Measurements of the Penetration Depth of MgB<sub>2</sub> and YBa<sub>2</sub>Cu<sub>3</sub>O<sub>7- $\delta$</sub> Superconductor Films by Using Sapphire Resonators with Short-Circuited Parallel Plates

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A measurement method that enables to measure the penetration depth ( $\lambda$ ) of superconductor films by using a short-ended parallel plate sapphire resonator is introduced. Variations in the  $\lambda$  of c-axis-oriented MgB<sub>2</sub> and YBa<sub>2</sub>Cu<sub>3</sub>O<sub>7-x</sub> films could be measured down to the lowest temperature using a sapphire resonator with a YBa<sub>2</sub>Cu<sub>3</sub>O<sub>7-x</sub> film at the bottom. A model equation of  $\lambda = \lambda_0 [1 - (\frac{T}{T_C})^\tau]^{1/2}$  for MgB<sub>2</sub> films appeared to describe the observed variations of the resonant frequency of the sapphire resonator with temperature, with  $\lambda_0$ ,  $\tau$ , and  $T_C$  used as the fitting parameters. Merits of using the sapphire resonators with short-circuited parallel plates are discussed.

Keywords: penetration depth, superconductor film, dielectric resonator, short-ended